

**Pr Ref: M4327G004**

| Sl. No. | ITI Code        | Description                                                                                        | Make                                              | MPN                   | PR Qty |
|---------|-----------------|----------------------------------------------------------------------------------------------------|---------------------------------------------------|-----------------------|--------|
| 1       | SA3C1142888E3T9 | VOLTAGE REGULATOR, SHUNT, ADJUSTABLE, MAX OUTPUT: 18V, 70mA, -40 TO +125 DEG CEL                   | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | TLVH431IDBZT          | 300    |
| 2       | SA3B2522889S4T2 | IC, SMD, CMOS, DUAL BIT BUS TRANSCEIVER, UQFN PACKAGE, 16 PIN, -40 TO +85 DEG CEL                  | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | SN74AVC4T245RSVR      | 300    |
| 3       | SA3B2012888E3T9 | IC, SMD, CMOS, SINGLE, 2 INPUT AND GATE, SOT-23 PACKAGE, 5 PIN, -40 TO +125 DEG CEL                | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | SN74LVC1G08DBVR       | 500    |
| 4       | SA3B2522873S4T9 | IC, USB TO UART BRIDGE, ETHERNET PHY TRANSCEIVER, 3.45V, VQFN 48 PIN, -40 TO +125 DEG CEL          | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | DP83869HMRGZT         | 280    |
| 5       | SA3B2522799S4T2 | IC, USB TO DUAL UART, CONTROL INTERFACE, QFN 24 PACKAGE, -40 TO +85 DEG CEL                        | SILICON LABS                                      | CP2105-F01-GM         | 200    |
| 6       | SA3C1142889S2T9 | IC, SMD, VOLTAGE REGULATOR, LDO, SINGLE OUTPUT, VSON 8 PACKAGE, -40 TO +125 DEG CEL                | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | TPS73701DRBT          | 200    |
| 7       | SA3B2372875S1T9 | IC, SMD, SINGLE BUS, BUFFER, OPEN DRAIN OUTPUT, NON INVERTING, SC70-5 PACAKGE, -40 TO +125 DEG CEL | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | SN74LVC1G07DCKT       | 550    |
| 8       | SA3B2052931S2T2 | IC, SMD, SPI NOR FLASH, 16Mb, WSON-8 PACKAGE, -40 TO +105 DEG CEL                                  | INNOVATIVE SYSTEMS                                | IS25LP016D-JKLE       | 260    |
| 9       | SA3C1142820S2T2 | IC, DDR MEMORY TERMINATION REGULATOR, 10-VSON PKG.,-40 TO 85 DEG. C                                | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | TPS51200DRCT          | 150    |
| 10      | SA3B2052906H1T2 | IC, SMD, FLASH, 512 Mb, 3V, SERIAL, 16 PIN SOP, -40 TO +85 °C                                      | MICRON                                            | MT25QL512ABB8ESF-OSIT | 150    |

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| 11      | SA3B2522891L9T9 | IC, SMD, CMOS, 8 BIT, DUAL SUPPLY BUS TRANSCEIVER, TSSOP PACKAGE, 24 PIN, -40 TO +125 DEG CEL    | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | SN74AVC8T245QPWRQ1   | 650    |
| 12      | SA3H1502871S2T7 | IC, MICROPROCESSOR, ARM CORTEX A15, CORTEX M4, 32 BIT, FCBGA 760 PIN, -40 DEG CEL TO 105 DEG CEL | TEXAS INSTRUMENTS PVT LTD(NATIONAL SEMICONDUCTOR) | AM5748ABZXEA         | 130    |
| 13      | SA3B2912867M4TD | IC, SMD, SDRAM, DDR3L, 512M x 16 BIT, 96 PIN FBGA, -40 TO +85 DEG. CEL                           | ALLIANCE MEMORY INC.                              | AS4C512M16D3LB-12BIN | 260    |